## NSN 5962-01-223-8468



standards, individual manufactureer standards, etc.).

-8468

| NSN 5962-01-223-8468<br>Memory Microcircuit - Page 1 of 1    |
|--|
| View Online at https://aerobasegroup.com/nsn/5962-01-223-    |
| Body Length:   |
| 0.785 inches   |
| Body Width:  |
| 0.271 inches   |
| Body Height:   |
| 0.185 inches   |
| Operating Tempurature Range:                                 |
| -55.0 to 125.0 degrees celsius                               |
| Storage Tempurature Range:                                   |
| -65.0 to 150.0 degrees celsius                               |
| Features Provided:   |
| Schottky and programmable and high speed                     |
| Inclosure Material:  |
| Ceramic  |
| Inclosure Configuration:                                     |
| Dual-in-line   |
| Output Logic Form:   |
| Transistor-transistor logic                                  |
| Input Circuit Pattern:                                       |
| 10 input   |
| Terminal Surface Treatment:                                  |
| Solder   |
| Voltage Rating And Type Per Characteristic:                  |
| 5.5 volts power source                                       |
| Memory Device Type:  |
| Rom  |
| Test Data Document:  |
| 96906-mil-std-883 standard (includes industry or association |
| Terminal Type And Quantity:                                  |
| 16 printed circuit   |
| Shelf Life:  |
| N/a  |
| Unit Of Measure:   |
|  |
| Demilitarization:  |
| Yes - demil/mli  |
| Fiig:  |
| A458a0   |
|  |
|  |
|  |
|  |